



SLLS505F - FEBRUARY 2002 - REVISED NOVEMBER 2003

3.3-V RS-485 TRANSCEIVERS

FEATURES

- Operates With a 3.3-V Supply
- Bus-Pin ESD Protection Exceeds 16 kV HBM
- 1/8 Unit-Load Option Available (Up to 256 Nodes on the Bus)
- Optional Driver Output Transition Times for Signaling Rates[†] of 1 Mbps, 10 Mbps and 25 Mbps
- Meets or Exceeds the Requirements of ANSI TIA/EIA-485-A
- Bus-Pin Short Circuit Protection From –7 V to 12 V
- Low-Current Standby Mode ... 1 μA Typical
- Open-Circuit, Idle-Bus, and Shorted-Bus Failsafe Receiver
- Thermal Shutdown Protection
- Glitch-Free Power-Up and Power-Down Protection for Hot-Plugging Applications
- SN75176 Footprint

APPLICATIONS

- Digital Motor Control
- Utility Meters
- Chassis-to-Chassis Interconnects
- Electronic Security Stations
- Industrial Process Control
- Building Automation
- Point-of-Sale (POS) Terminals and Networks

DESCRIPTION

The SN65HVD10. SN75HVD10, SN65HVD11. SN75HVD11, SN65HVD12, and SN75HVD12 combine a 3-state differential line driver and differential input line receiver that operate with a single 3.3-V power supply. They are designed for balanced transmission lines and meet or exceed ANSI standard TIA/EIA-485-A and ISO 8482:1993. These differential bus transceivers are monolithic integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. The drivers and receivers have active-high and active-low enables respectively, that can be externally connected together to function as direction control. Very low device standby supply current can be achieved by disabling the driver and the receiver.

The driver differential outputs and receiver differential inputs connect internally to form a differential input/ output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. These parts feature wide positive and negative common-mode voltage ranges, making them suitable for party-line applications.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

[†]The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

		_	PACKAGE		
SIGNALING RATE	UNIT LOADS	TA	SOIC(1)	PDIP	SOIC MARKING
25 Mbps	1/2		SN65HVD10D	SN65HVD10P	VP10
10 Mbps	1/8	-40°C to 85°C	SN65HVD11D	SN65HVD11P	VP11
1 Mbps	1/8		SN65HVD12D	SN65HVD12P	VP12
25 Mbps	1/2		SN75HVD10D	SN75HVD10P	VN10
10 Mbps	1/8	−0°C to 70°C	SN75HVD11D	SN75HVD11P	VN11
1 Mbps	1/8		SN75HVD12D	SN75HVD12P	VN12
25 Mbps	1/2	4000 1- 40500	SN65HVD10QD	SN65HVD10QP	VP10Q
10 Mbps	1/8	-40°C to 125°C	SN65HVD11QD	SN65HVD11QP	VP11Q

(1) The D package is available taped and reeled. Add an R suffix to the part number (i.e., SN75HVD11DR).

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted(1) (2)

			SN65HVD10, SN75HVD10 SN65HVD11, SN75HVD11 SN65HVD12, SN75HVD12	
Supply voltage range, V _{CC}			–0.3 V to 6 V	
Voltage range at A or B			–9 V to 14 V	
Input voltage range at D, DE,	-0.5 V to V _{CC} + 0.5 V			
Voltage input range, transient p	ulse, A and B, through 100 Ω (see Figur	re 11)	–50 V to 50 V	
	11	A, B and GND	16 kV	
Electrostatic discharge	Human body model(3)	All pins	4 kV	
	Charged-device model ⁽⁴⁾	All pins Charge	1 kV	
Continuous total power dissip	ation	·	See Dissipation Rating Table	
Junction temperature, TJ	Junction temperature, TJ			
Storage temperature range, T	stg		–65°C to 150°C	
Lead temperature 1,6 mm (1/	16 inch) from case for 10 seconds		260°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.

⁽⁴⁾ Tested in accordance with JEDEC Standard 22, Test Method C101.

PACKAGE DISSIPATION RATINGS

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D(2)	597 mW	4.97 mW/°C	373 mW	298 mW	100 mW
D(3)	990 mW	8.26 mW/°C	620 mW	496 mW	165 mW
Р	1290 mW	10.75 mW/°C	806 mW	645 mW	215 mW

(1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

(2) Tested in accordance with the Low-K thermal metric definitions of EIA/JESD51-3.

(3) Tested in accordance with the High-K thermal metric definitions of EIA/JESD51-7.



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RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		3		3.6	V
Voltage at any bus terminal (separately or common mode) $V_{\mbox{I}}$ or $V_{\mbox{IC}}$		_7(1)		12	V
High-level input voltage, VIH	D, DE, RE	2		VCC	V
Low-level input voltage, VIL	D, DE, RE	0		0.8	V
Differential input voltage, VID (see Figure 7)	·	-12		12	V
	Driver	-60			
High-level output current, IOH	Receiver	-8			mA
Level and ended animated	Driver			60	
Low-level output current, IOL	Receiver			8	mA
Differential load resistance, RL		54	60		Ω
Differential load capacitance, CL			50		pF
	HVD10			25	
Signaling rate	HVD11			10	Mbps
	HVD12			1	1
Junction temperature, TJ ⁽²⁾				145	°C

(1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

(2) See thermal characteristics table for information regarding this specification.

DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS		MIN	ТҮР(1)	MAX	UNIT	
VIK	Input clamp voltage		lj = -18 mA		-1.5			V
			IO = 0		2		VCC	
IVODI	Differential output voltage ⁽²⁾		R _L = 54 Ω, See	Figure 1	1.5			V
			$V_{test} = -7 V to 7$	12 V, See Figure 2	1.5			
$\Delta V_{OD} $	Change in magnitude of differential output voltage		See Figure 1 an	d Figure 2	-0.2		0.2	V
VOC(PP)	Peak-to-peak common-mode output voltage	ge				400		mV
VOC(SS)	Steady-state common-mode output voltage	е	See Figure 3		1.4		2.5	V
∆VOC(SS)	Change in steady-state common-mode ou voltage	tput			-0.05		0.05	V
IOZ	High-impedance output current		See receiver input currents					
1.		D			-100		0	A
1	Input current	DE			0		100	μA
los	Short-circuit output current		$-7 \text{ V} \le \text{V}_0 \le 12$	V	-250		250	mA
C _(OD)	Differential output capacitance		$V_{OD} = 0.4 \sin(4$	4E6πt) + 0.5 V, DE at 0 V		16		pF
			RE at V _{CC} , D & DE at V _{CC,} No load	Receiver disabled and driver enabled		9	15.5	mA
ICC	Supply current		RE at V _{CC} , D at V _{CC} , DE at 0 V, No load	Receiver disabled and driver disabled (standby)		1	5	μΑ
(4)			RE at 0 V, D & DE at V _{CC} , No load	Receiver enabled and driver enabled		9	15.5	mA

(1) All typical values are at 25° C and with a 3.3-V supply.

(2) For $T_A > 85^{\circ}C$, V_{CC} is ±5%.

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DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted



	PARAMETER		TEST CONDITIONS	MIN	түр(1)	MAX	UNIT
		HVD10		5	8.5	16	
^t PLH	Propagation delay time, low-to-high-level output	HVD11		18	25	40	ns
		HVD12		135	200	300	
		HVD10		5	8.5	16	
^t PHL	Propagation delay time, high-to-low-level output	HVD11		18	25	40	ns
		HVD12	-	135	200	300	
		HVD10	1	3	4.5	10	
tr	Differential output signal rise time	HVD11	$R_L = 54 \Omega$, $C_L = 50 pF$, See Figure 4	10	20	30	ns
		HVD12	- See Figure 4	100	170	300	
		HVD10		3	4.5	10	
tf	Differential output signal fall time	HVD11		10	20	30	ns
		HVD12		100	170	300	
		HVD10	-			1.5	
^t sk(p)	Pulse skew (tpHL - tpLH)	HVD11	-			2.5	ns
5K(p)		HVD12	-			7	
		HVD10				6	
^t sk(pp) ⁽²⁾	Part-to-part skew	HVD11	-			11	ns
GR(pp)		HVD12	-	100			
		HVD10				31	
^t PZH	Propagation delay time,	HVD11	-			55 ns	
1 211	high-impedance-to-high-level output	HVD12	$R_L = 110 \Omega$, \overline{RE} at 0 V,			300	
		HVD10			25		
^t PHZ	Propagation delay time,	HVD11	-			55	ns
	high-level-to-high-impedance output	HVD12	-			300	
		HVD10				26	
^t PZL	Propagation delay time,	HVD11	-			55	ns
1 26	high-impedance-to-low-level output	HVD12	$R_L = 110 \Omega$, \overline{RE} at 0 V,			300	
		HVD10	See Figure 6			26	
^t PLZ	Propagation delay time,	HVD11			75	_	
	low-level-to-high-impedance output	HVD12				400	
^t PZH	Propagation delay time, standby-to-high-level outp		$R_L = 110 \Omega$, \overline{RE} at 3 V, See Figure 5			6	μs
^t PZL	Propagation delay time, standby-to-low-level output	ıt	R _L = 110 Ω, \overline{RE} at 3 V, See Figure 6			6	μs

(1) All typical values are at 25°C and with a 3.3-V supply.
(2) t_{Sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.



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RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS			MIN	түр(1)	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	I _O = -8 mA					-0.01	
VIT-	Negative-going input threshold voltage	I _O = 8 mA			-0.2			V
V _{hys}	Hysteresis voltage (VIT+ - VIT-)					35		mV
VIK	Enable-input clamp voltage	Ij = -18 mA			-1.5			V
VOH	High-level output voltage	$V_{ID} = 200 \text{ mV},$	$I_{OH} = -8 \text{ mA},$	See Figure 7	2.4			V
VOL	Low-level output voltage	$V_{ID} = -200 \text{ mV},$	I _{OL} = 8 mA,	See Figure 7			0.4	V
IOZ	High-impedance-state output current	AO = 0 or ACC	RE at V _{CC}		-1		1	μΑ
		$V_A \text{ or } V_B = 12 \text{ V}$				0.05	0.11	
		$V_A \text{ or } V_B = 12 \text{ V},$	Λ CC = 0 Λ	HVD11, HVD12,		0.06	0.13	
		$V_A \text{ or } V_B = -7 \text{ V}$		Other input at 0 V	-0.1	-0.05		mA
		$V_A \text{ or } V_B = -7 \text{ V}, V_{CC} = 0 \text{ V}$		-0.05	-0.04			
II	Bus input current	$V_A \text{ or } V_B = 12 \text{ V}$				0.2	0.5	
		$V_A \text{ or } V_B = 12 \text{ V},$	VCC = 0 V	HVD10,		0.25	0.5	
		$V_A \text{ or } V_B = -7 \text{ V}$		Other input at 0 V	-0.4	-0.2		mA
		V_A or $V_B = -7$ V,	Λ CC = 0 Λ		-0.4	-0.15		
Iн	High-level input current, RE	V _{IH} = 2 V		÷	-30		0	μΑ
۱ _{IL}	Low-level input current, RE	V _{IL} = 0.8 V			-30		0	μΑ
C _{ID}	Differential input capacitance	V _{ID} = 0.4 sin (4E6	πt) + 0.5 V, DE a	at 0 V		15		pF
		RE at 0 V, D & DE at 0 V, No load	Receiver enable disabled	ed and driver		4	8	mA
ICC	Supply current	RE at V _{CC} , D at V _{CC} , DE at 0 V, No load	Receiver disabl disabled (stand			1	5	μΑ
		RE at 0 V, D & DE at V _{CC} , No load	Receiver enable	ed and driver		9	15.5	mA

(1) All typical values are at 25°C and with a 3.3-V supply.

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RECEIVER SWITCHING CHARACTERISTICS

TEXAS INSTRUMENTS www.ti.com

over recommended operating conditions unless otherwise noted

	PARAMETER		TEST CONDITIONS	MIN	ТҮР(1)	MAX	UNIT	
^t PLH	Propagation delay time, low-to-high-level output	HVD10		12.5	20	25		
^t PHL	Propagation delay time, high-to-low-level output	HVD10]	12.5	20	25	ns	
^t PLH	Propagation delay time, low-to-high-level output	HVD11 HVD12		30	55	70	ns	
^t PHL	Propagation delay time, high-to-low-level output	HVD11 HVD12	V _{ID} = –1.5 V to 1.5 V, C _L = 15 pF, See Figure 8	30	55	70	ns	
		HVD10				1.5		
^t sk(p)	Pulse skew (tpHL - tpLH)	HVD11				4	ns	
(1)		HVD12				4	-	
		HVD10				8		
^t sk(pp) ⁽²⁾	Part-to-part skew	HVD11				15	5 ns	
- (17)		HVD12				15		
t _r	Output signal rise time			1	2	5		
t _f	Output signal fall time		$C_L = 15 \text{ pF}$, See Figure 8	1	2	5	ns	
^t PZH ⁽¹⁾	Output enable time to high level					15		
t _{PZL} (1)	Output enable time to low level		C _L = 15 pF, DE at 3 V,			15		
^t PHZ	PHZ Output disable time from high level		See Figure 9			20	ns	
^t PLZ						15		
t _{PZH} ⁽²⁾	Propagation delay time, standby-to-high-level outp	out	C _L = 15 pF, DE at 0,	6		6		
t _{PZL} (2)	Propagation delay time, standby-to-low-level outp	ut	See Figure 10			6	μs	

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

THERMAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted⁽¹⁾

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS	
0	(2)	High–K board ⁽³⁾ , No airflow	D pkg		121		
θJA	Junction-to-ambient thermal resistance(2)	No airflow ⁽⁴⁾	P pkg		93		°C/W
•		High–K board	D pkg		67		°C/W
θJΒ	Junction-to-board thermal resistance	See Note (4)	P pkg		57		°C/W
•			D pkg		41		
θͿϹ	Junction-to-case thermal resistance		P pkg	55			°C/W
		R _L = 60Ω, C _L = 50 pF, DE at V _{CC} RE at 0 V, Input to D a 50% duty cycle square	HVD10 (25 Mbps)		198	233	mW
PD	Device power dissipation		HVD11 (10 Mbps)		141	176	mW
		wave at indicated signaling rate	HVD12 (500 kbps)		133	161	mW
-	A 11 A 14 A	High–K board, No airflow	D pkg	-40		116	
т _А	Ambient air temperature	No airflow ⁽⁴⁾	P pkg	-40		123	°C
TJSD	Thermal shutdown junction temperature				165		°C

⁽¹⁾ See Application Information section for an explanation of these parameters.

(2) The intent of θ_{JA} specification is solely for a thermal performance comparison of one package to another in a standardized environment. This methodology is not meant to and will not predict the performance of a package in an application-specific environment.

(3) JSD51-7, High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages.

(4) JESD51–10, Test Boards for Through-Hole Perimeter Leaded Package Thermal Measurements.



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PARAMETER MEASUREMENT INFORMATION



Figure 1. Driver V_{OD} Test Circuit

and Voltage and Current Definitions



Figure 2. Driver V_{OD} With Common-Mode Loading Test Circuit



Input: PRR = 500 kHz, 50% Duty Cycle,tr<6ns, tf<6ns, ZO = 50 Ω

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



Generator: PRR = 500 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z₀ = 50 Ω





Generator: PRR = 500 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z_0 = 50 Ω

Figure 5. Driver High-Level Enable and Disable Time Test Circuit and Voltage Waveforms

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Generator: PRR = 500 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z₀ = 50 Ω

Figure 6. Driver Low-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms



Figure 7. Receiver Voltage and Current Definitions



Generator: PRR = 500 kHz, 50% Duty Cycle, tr <6 ns, tf <6 ns, Zo = 50 Ω



Figure 8. Receiver Switching Test Circuit and Voltage Waveforms



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Generator: PRR = 500 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z₀ = 50 Ω



Figure 9. Receiver Enable and Disable Time Test Circuit and Voltage Waveforms With Drivers Enabled

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Generator: PRR = 100 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z₀ = 50 Ω



Figure 10. Receiver Enable Time From Standby (Driver Disabled)









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Function Tables

2								
INPUT	ENABLE	OUTPUTS						
D	DE	Α	В					
Н	н	Н	L					
L	Н	L	Н					
Х	L	Z	Z					
Open	Н	Н	L					

RECEIVER

DIFFERENTIAL INPUTS	ENABLE	OUTPUT
$V_{ID} = V_A - V_B$	RE	R
V _{ID} ≤ -0.2 V	L	L
−0.2 V < V _{ID} < −0.01 V	L	?
–0.01 V ≤ V _{ID}	L	Н
Х	Н	Z
Open Circuit	L	Н
Short Circuit	L	Н

H = high level; L = low level; Z = high impedance; X = irrelevant; ? = indeterminate

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EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



	R1/R2	R3
SN65HVD10	9 k Ω	45 k Ω
SN65HVD11	36 k Ω	180 k Ω
SN65HVD12	36 k Ω	180 k Ω

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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS



Figure 20





APPLICATION INFORMATION



Device	Number of Devices on Bus	
HVD10	64	
HVD11	256	
HVD12	256	

NOTE: The line should be terminated at both ends with its characteristic impedance (R_T = Z_O). Stub lengths off the main line should be kept as short as possible.



Figure 21. Typical Application Circuit



An example application for the HVD12 is illustrated in Figure 21. Two HVD12 transceivers are used to communicate data through a 2000 foot (600 m) length of Commscope 5524 category 5e+ twisted pair cable. The

bus is terminated at each end by a 100- Ω resistor, matching the cable characteristic impedance. Figure 22 illustrates operation at a signaling rate of 250 kbps.



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THERMAL CHARACTERISTICS OF IC PACKAGES

 θ_{JA} (Junction-to-Ambient Thermal Resistance) is defined as the difference in junction temperature to ambient temperature divided by the operating power.

 θ_{JA} is *not* a constant and is a strong function of:

- the PCB design (50% variation)
- altitude (20% variation)
- device power (5% variation)

 θ_{JA} can be used to compare the thermal performance of packages if the specific test conditions are defined and used. Standardized testing includes specification of PCB construction, test chamber volume, sensor locations, and the thermal characteristics of holding fixtures. θ_{JA} is often misused when it is used to calculate junction temperatures for other installations.

TI uses two test PCBs as defined by JEDEC specifications. The low-k board gives *average* in-use condition thermal performance, and it consists of a single copper trace layer 25 mm long and 2-oz thick. The high-k board gives *best case* in-use condition, and it consists of two 1-oz buried power planes with a single copper trace layer 25 mm long and 2-oz thick. A 4% to 50% difference in θ_{JA} can be measured between these two test cards

 θ_{JC} (Junction-to-Case Thermal Resistance) is defined as difference in junction temperature to case divided by the operating power. It is measured by putting the mounted package up against a copper block cold plate to force heat to flow from die, through the mold compound into the copper block.

 θ_{JC} is a useful thermal characteristic when a heatsink is applied to package. It is *not* a useful characteristic to predict junction temperature because it provides pessimistic numbers if the case temperature is measured in a nonstandard system and junction temperatures are backed out. It can be used with θ_{JB} in 1-dimensional thermal simulation of a package system.

 θ_{JB} (Junction-to-Board Thermal Resistance) is defined as the difference in the junction temperature and the PCB temperature at the center of the package (closest to the die) when the PCB is clamped in a cold-plate structure. θ_{JB} is only defined for the high-k test card.

 θ_{JB} provides an overall thermal resistance between the die and the PCB. It includes a bit of the PCB thermal resistance (especially for BGA's with thermal balls) and can be used for simple 1-dimensional network analysis of package system (see Figure 23).



Figure 23. Thermal Resistance

MECHANICAL DATA

MPDI001A - JANUARY 1995 - REVISED JUNE 1999



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AA.



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